

FORM 5

CHAPTER 5

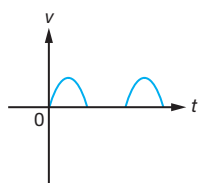
Paper 1

- 1 B 2 A 3 B 4 D 5 D
6 C 7 B 8 D 9 D 10 A

Paper 2

Structured Question

- 1 (a) pnp type transistor.
(b) (i) 4.2 V
(ii) 6×10^{-5} A
(c) When the LDR is in the bright state, the base circuit will be activated. A larger current flow in the collector circuit and causes the light emitting diode to light up.
- 2 (a) To accelerate electrons from the cathode to the anode.
(b) (i) Heating the cathode so that electrons are released.
(ii) Produces light when struck by electrons.
(c) 2.98×10^7 m s⁻¹
(d) (i) The green light area dimmed.
(ii) Electrons are less energetic due to the lower acceleration potential difference and this causes the brightness of the green light to decrease.
- 3 (a) Silicon
(b) (i) The diode in the circuit *P* is connected in reverse bias while the diode in the circuit *Q* is connected in forward bias.
(ii) The bulb in the circuit *P* does not light up while the bulb in the circuit *Q* lights up.
(c) The bulb only lights up when the diode is forward biased.
(d) (i)



- (ii) Rectification

Essay Questions

- 4 (a) The process of inserting a small, controlled number of impurities into the lattice of a pure semiconductor crystal.

| Material | Conductivity |
|---------------|--|
| Conductor | High |
| Insulation | Low |
| Semiconductor | Low at low temperature, high at high temperature |

| | Majority charge carriers | Minority charge carriers |
|-----------------------------|--------------------------|--------------------------|
| Semiconductor type <i>p</i> | Hollow | Free electrons |
| Semiconductor type <i>n</i> | Free electrons | Hollow |

| Appropriate features | Reason |
|--|---|
| A substance with 4 valence electrons | Pentavalent or trivalent elements can be easily doped into them to form <i>p</i> type or <i>n</i> type semiconductors |
| Highest melting point | So that the material does not melt at high temperatures |
| Solid state | Materials can be easily formed into various types of components |
| Resistivity at room temperature | Current can flow through it easily |
| Material <i>C</i> is the most suitable | Because it has 4 valence electrons, its highest melting point, in the solid state and low resistivity at room temperature |

- (e) (i) A diode only allows current to flow in one direction only
(ii)

